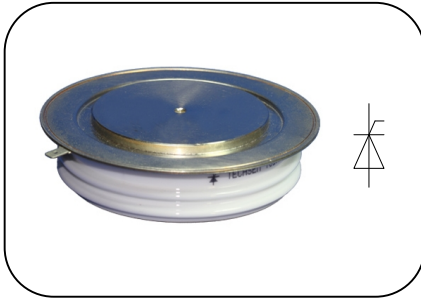


**Features**

Interdigitated amplifying gates
Fast turn-on and high di/dt
Low switching losses

Typical Applications

Inductive heating
Electronic welders
Self-commutated inverters

Part No. Y65KKE-KT60cT

I_{T(AV)}	2080A		
V_{DRM}, V_{RRM}	800V	1000V	
	1200V	1400V	
	1600V	1800V	
t_q	18~50μs		

SYMBOL	CHARACTERISTIC	TEST CONDITIONS	T_J (°C)	VALUE			UNIT
				Min	Type	Max	
$I_{T(AV)}$	Mean on-state current	180 half sine wave 50Hz Double side cooled, $T_C=55^{\circ}\text{C}$	125			2080	A
V_{DRM} V_{RRM}	Repetitive peak off-state voltage Repetitive peak reverse voltage	$t_p=10\text{ms}$	125	800		1800	V
I_{DRM} I_{RRM}	Repetitive peak current	at V_{DRM} at V_{RRM}	125			120	mA
I_{TSM}	Surge on-state current	10ms half sine wave	125			21	kA
I^2t	I^2t for fusing coordination					2205	$\text{A}^2\text{s} \times 10^3$
V_{TO}	Threshold voltage		125			1.41	V
r_T	On-state slope resistance					0.23	mΩ
V_{TM}	Peak on-state voltage	$I_{TM}=4000\text{A}$, $F=32\text{kN}$	25			3.15	V
dv/dt	Critical rate of rise of off-state voltage	$V_{DM}=0.67V_{DRM}$	125			1000	V/μs
di/dt	Critical rate of rise of on-state current	$V_{DM}=67\%V_{DRM}$ to 3000A Gate pulse $t_r \leq 0.5\mu\text{s}$ $I_{GM}=1.5\text{A}$ Single pulse	125			1200	A/μs
Q_{rr}	Recovery charge	$I_{TM}=2000\text{A}$, $t_p=4000\mu\text{s}$, $di/dt=-20\text{A}/\mu\text{s}$, $V_R=100\text{V}$	125		860		μC
t_q	Circuit commutated turn-off time	$I_{TM}=2000\text{A}$, $t_p=4000\mu\text{s}$, $V_R=100\text{V}$ $dv/dt=30\text{V}/\mu\text{s}$, $di/dt=-20\text{A}/\mu\text{s}$	125	18		50	μs
I_{GT}	Gate trigger current	$V_A=12\text{V}$, $I_A=1\text{A}$	25	40		400	mA
V_{GT}	Gate trigger voltage			0.9		4.0	V
I_H	Holding current			20		800	mA
I_L	Latching current					1000	mA
V_{GD}	Non-trigger gate voltage	$V_{DM}=67\%V_{DRM}$	125			0.3	V
$R_{th(j-c)}$	Thermal resistance Junction to case	At 180° sine double side cooled Clamping force 32kN				0.013	C /W
$R_{th(c-h)}$	Thermal resistance case to heat sink					0.0035	
F_m	Mounting force			27		34	kN
T_{vj}	Junction temperature			-40		125	°C
T_{stg}	Stored temperature			-40		140	°C
W_i	Weight				820		g
Outline	KT60cT						

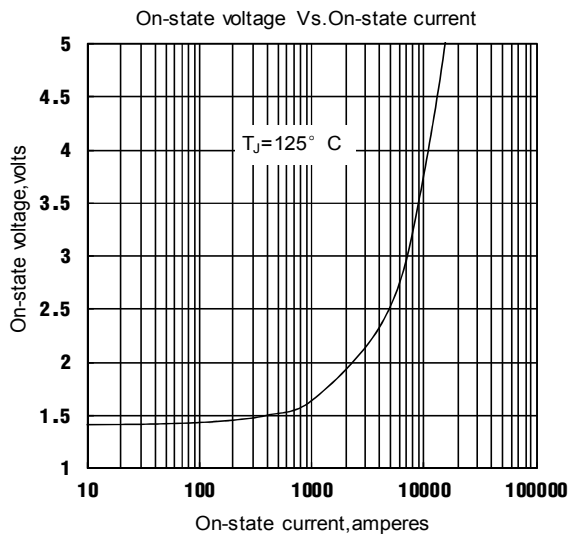


Fig.1

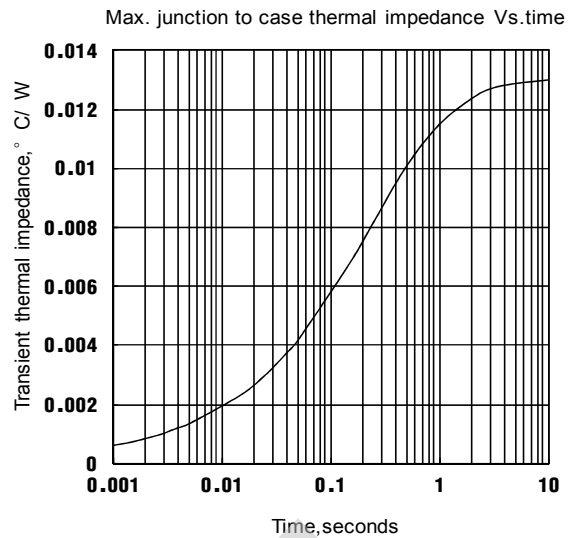


Fig.2

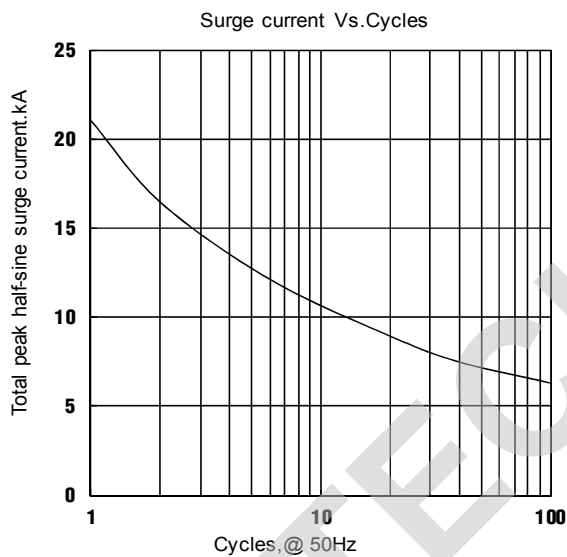


Fig.3

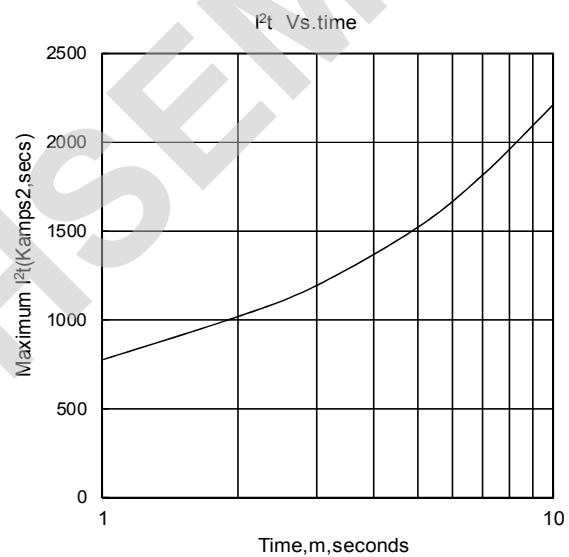


Fig.4

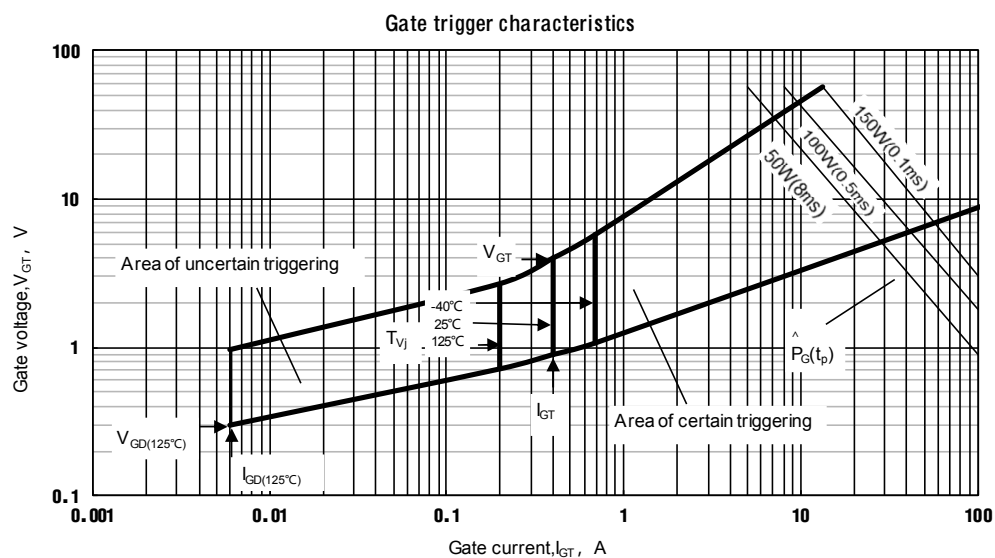
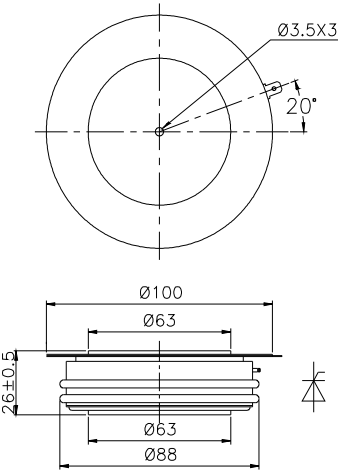


Fig.5

Outline:



TECHSEM reserves the right to change specifications without notice.